

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
1	BRS	L1	6849	((compound adj semiconductor) or (III-V) or (II-VI) or nitride or arsenide or selenide or antimonide) not (seed) and ((single adj crystal\$4) or (mono\$1crystal\$4)) and (vertical or Bridgman or Bridgeman)	USPAT; US-PGP UB; EPO; JPO; DERWE NT; IBM_TD B	2002/01/24 06:32	
2	IS&R	L2	1012	(117/73-83).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWE NT; IBM_TD B	2002/01/24 06:33	
3	BRS	L4	45	1 and 2	USPAT; US-PGP UB; EPO; JPO; DERWE NT; IBM_TD B	2002/01/24 06:35	
4	BRS	L5	1250	(no adj seed) or (without near1 seed) and crystal	USPAT; US-PGP UB; EPO; JPO; DERWE NT; IBM_TD B	2002/01/24 06:37	
5	BRS	L6	16	5 and (2 or 1)	USPAT; US-PGP UB; EPO; JPO; DERWE NT; IBM_TD B	2002/01/24 06:53	
6	BRS	L7	28858	((compound adj semiconductor) or (III-V) or (II-VI) or nitride or arsenide or selenide or antimonide or phosphide or selenide or telluride) and ((single adj crystal\$4) or (mono\$1crystal\$4))	USPAT; US-PGP UB; EPO; JPO; DERWE NT; IBM_TD B	2002/01/24 06:52	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
7	BRS	L8	52	5 and (2 or 7)	USPAT; US-PGP UB; EPO; JPO; DERWE NT; IBM_TD B	2002/01/24 08:30	
8	BRS	L9	26	unnecessary near seed	USPAT; US-PGP UB; EPO; JPO; DERWE NT; IBM_TD B	2002/01/24 08:30	

	Type	Hits	Search Text	DBs
1	BRS	6829	((compound adj semiconductor) or (III-V) or (II-VI) or nitride or arsenide or selenide or antimonide) not (seed) and ((single adj crystal\$4) or (mono\$1crystal\$4)) and (vertical or Bridgman or Bridgeman)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	74	((compound adj semiconductor) or (III-V) or (II-VI) or nitride or arsenide or selenide or antimonide) not (seed) and ((single adj crystal\$4) or (mono\$1crystal\$4)) and (vertical or Bridgman or Bridgeman)) and (VGF or VB)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	2391	((compound adj semiconductor) or (III-V) or (II-VI) or nitride or arsenide or selenide or antimonide) not (seed) and ((single adj crystal\$4) or (mono\$1crystal\$4)) and (vertical or Bridgman or Bridgeman) and (melt or liquid or (raw adj material))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	481	((compound adj semiconductor) or (III-V) or (II-VI) or nitride or arsenide or selenide or antimonide) not (seed) and ((single adj crystal\$4) or (mono\$1crystal\$4)) and (vertical or Bridgman or Bridgeman) and (melt or liquid or (raw adj material))) and (nucle\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	IS&R	1012	(117/73-83).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB